

International **IR** Rectifier

244NQ... SERIES

SCHOTTKY RECTIFIER

240 Amp

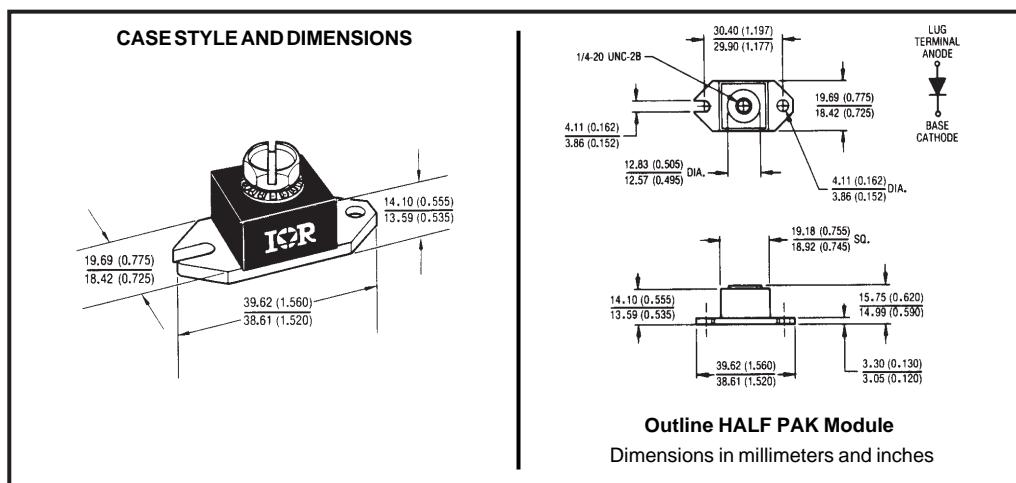
Major Ratings and Characteristics

Characteristics	244NQ...	Units
$I_{F(AV)}$ Rectangular waveform	240	A
V_{RRM} range	35 to 45	V
I_{FSM} @ $t_p=5\mu s$ sine	35,000	A
V_F @ 240Apk, $T_J=100^\circ C$	0.52	V
T_J range	-55 to 125	°C

Description/Features

The 244NQ high current Schottky rectifier modules have been optimized for extremely low forward voltage drop, with higher leakage. The proprietary barrier technology allows for reliable operation up to $125^\circ C$ junction temperature. Typical applications are in switching power supplies, converters, free-wheeling diodes, welding and reverse battery protection.

- $125^\circ C T_J$ operation
- Unique high power, Half-Pak module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Extremely low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Voltage Ratings

Part number	244NQ035	244NQ040	244NQ045
V_R Max. DC Reverse Voltage (V)	35	40	45
V_{RWM} Max. Working Peak Reverse Voltage (V)			

Absolute Maximum Ratings

Parameters	244NQ	Units	Conditions		
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 5	240	A	50% duty cycle @ $T_c = 75^\circ C$, rectangular wave form		
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 7	35,000	A	5μs Sine or 3μs Rect. pulse	Following any rated load condition and with rated V_{RRM} applied	
	3800		10ms Sine or 6ms Rect. pulse		
E_{AS} Non-Repetitive Avalanche Energy	270	mJ	$T_j = 25^\circ C$, $I_{AS} = 40$ Amps, $L = 0.34$ mH		
I_{AR} Repetitive Avalanche Current	40	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_j max. $V_A = 1.5 \times V_R$ typical		

Electrical Specifications

Parameters	244NQ	Units	Conditions		
V_{FM} Max. Forward Voltage Drop (1) * See Fig. 1	0.55	V	@ 240A	$T_j = 25^\circ C$	
	0.73	V	@ 480A		
	0.52	V	@ 240A	$T_j = 100^\circ C$	
	0.72	V	@ 480A		
I_{RM} Max. Reverse Leakage Current (1) * See Fig. 2	20	mA	$T_j = 25^\circ C$	$V_R = \text{rated } V_R$	
	2400	mA	$T_j = 125^\circ C$		
C_T Max. Junction Capacitance	10,300	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) $25^\circ C$		
L_S Typical Series Inductance	5.0	nH	From top of terminal hole to mounting plane		
dv/dt Max. Voltage Rate of Change (Rated V_R)	10,000	V/ μs			

(1) Pulse Width < 300μs, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	244NQ	Units	Conditions	
T_j Max. Junction Temperature Range	-55 to 125	°C		
T_{stg} Max. Storage Temperature Range	-55 to 125	°C		
R_{thJC} Max. Thermal Resistance Junction to Case	0.20	°C/W	DC operation * See Fig. 4	
R_{thCS} Typical Thermal Resistance, Case to Heatsink	0.15	°C/W	Mounting surface, smooth and greased	
wt Approximate Weight	25.6(0.9)	g(oz.)		
T Mounting Torque	Min.	40(35)	Kg-cm (lbf-in)	Non-lubricated threads
	Max.	58(50)		
Terminal Torque	Min.	58(50)		
	Max.	86(75)		
Case Style	HALF PAK Module			

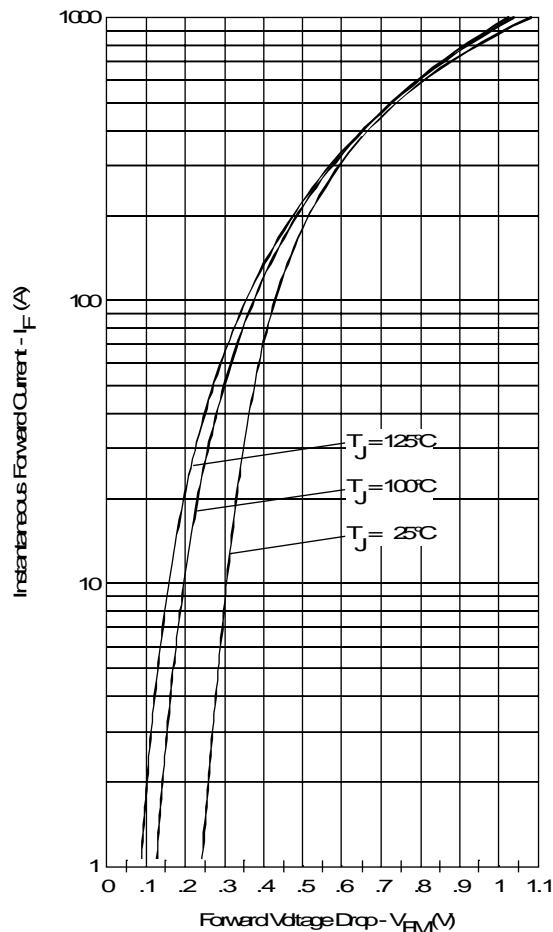


Fig.1-Maximum Forward Voltage Drop Characteristics

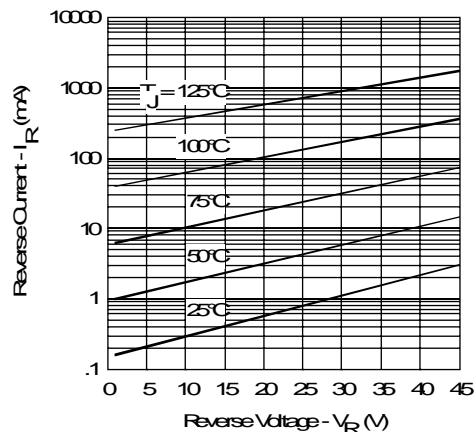


Fig.2-Typical Values of Reverse Current Vs. Reverse Voltage

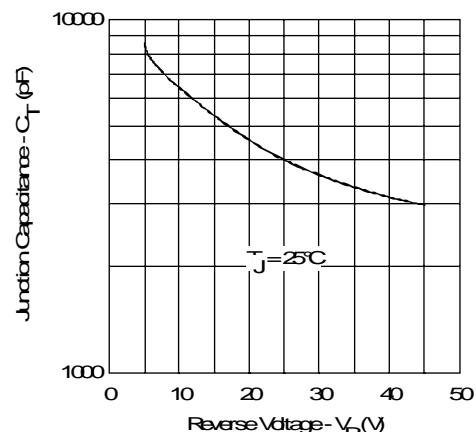


Fig.3-Typical Junction Capacitance Vs. Reverse Voltage

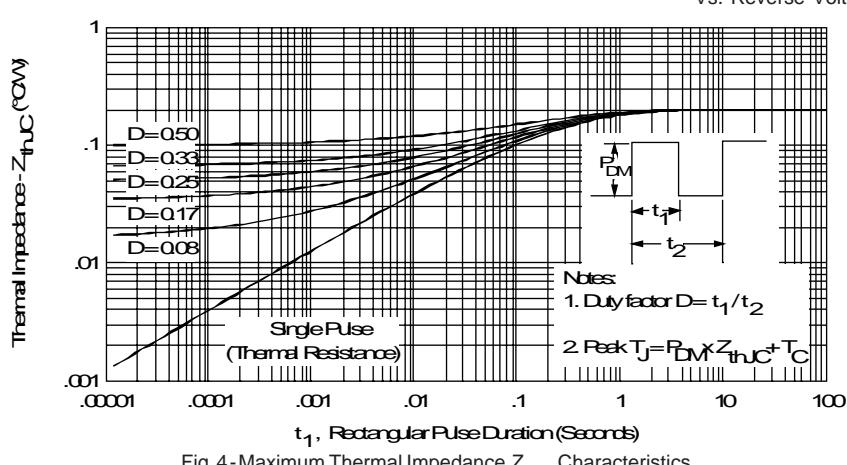


Fig.4-Maximum Thermal Impedance Z_{thJC} Characteristics

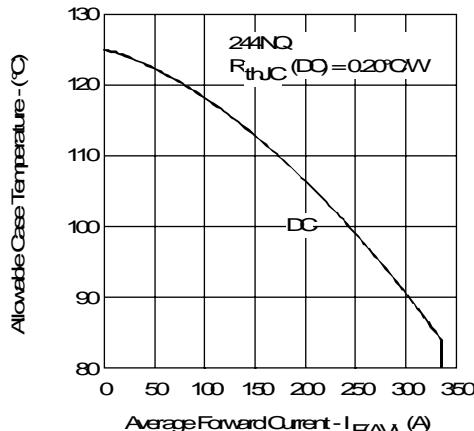


Fig.5-Maximum Allowable Case Temperature Vs. Average Forward Current

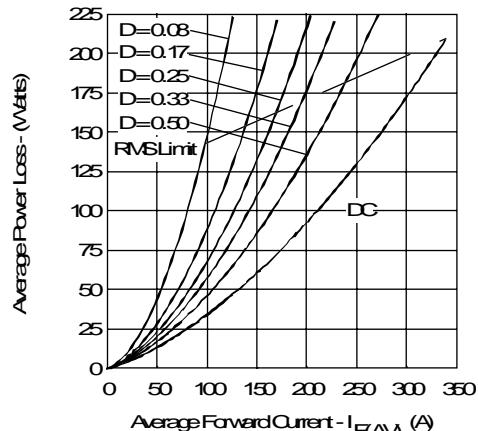


Fig.6-Forward Power Loss Characteristics

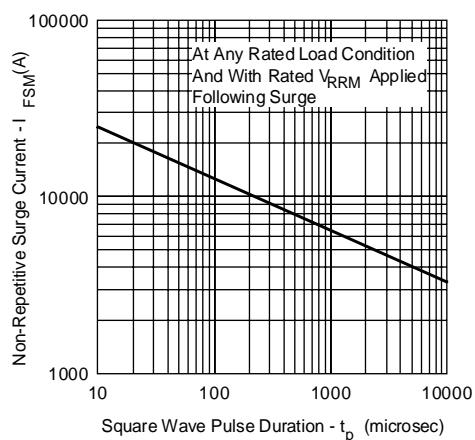


Fig.7-Maximum Non-Repetitive Surge Current

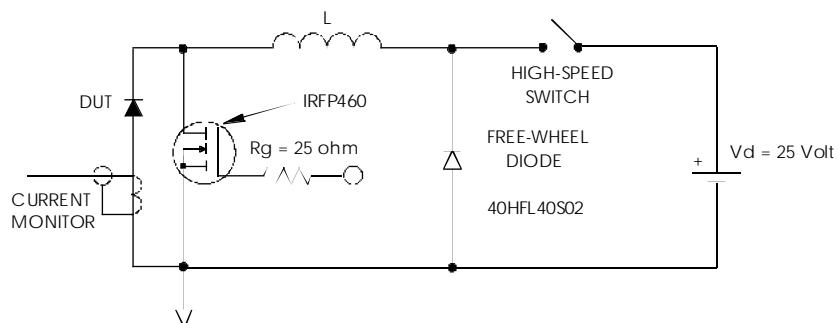


Fig.8-Unclamped Inductive Test Circuit